

## Analog IC Design

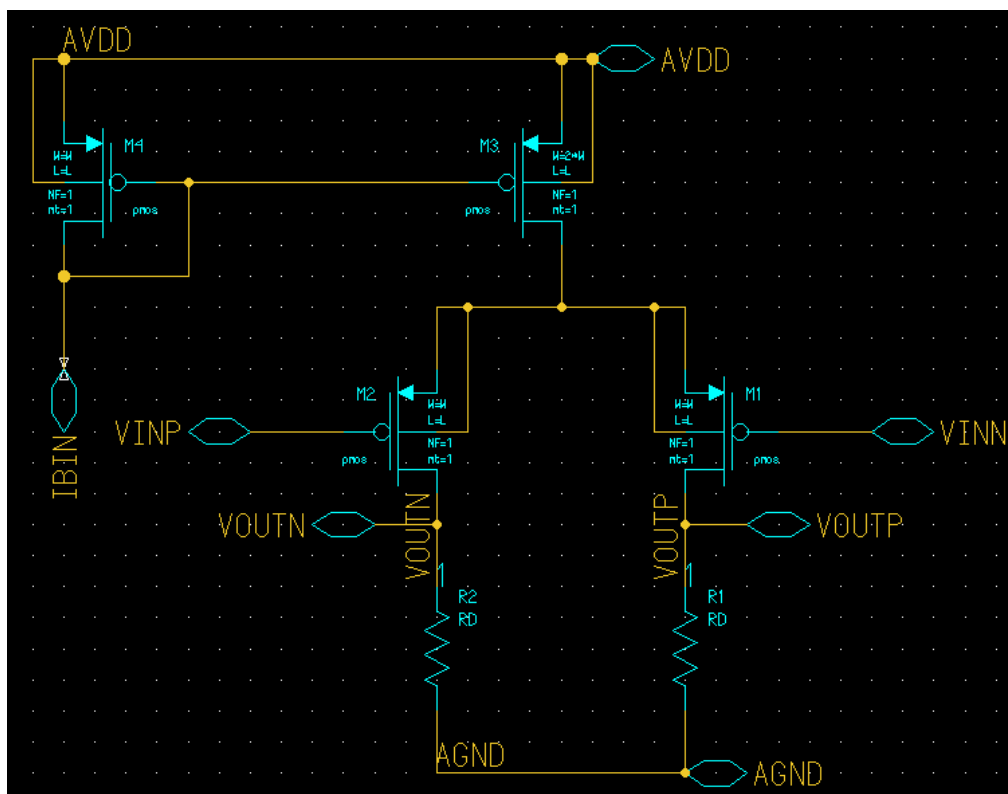
### Lab 06

### Differential Amplifier

## Intended Learning Objectives

In this lab you will:

- Design and simulate a differential amplifier.
- Learn how to simulate the small-signal differential characteristics of a differential amplifier.
- Learn how to simulate the small-signal common-mode characteristics of a differential amplifier.
- Learn how to simulate the large-signal differential characteristics of a differential amplifier.
- Learn how to simulate the large-signal common-mode characteristics of a differential amplifier.



## PART 1: Sizing Chart

1) We can show that the intrinsic gain of a MOSFET is given by

$$|A_v| \approx g_m r_o = \frac{2I_D}{V_{ov}} \times \frac{V_A}{I_D} = \frac{2V_A}{V_{ov}}$$

Interestingly, the gain only depends on  $\lambda$  and  $V_{ov}$ . However, to derive this expression we used  $g_m = \frac{2I_D}{V_{ov}}$  which is based on the square-law. For a real MOSFET, if we compute  $V_{ov}$  and  $\frac{2I_D}{g_m}$  they will not be equal. Let's define a new parameter called V-star ( $V^*$ ) which is calculated from actual simulation data using the formula

$$V^* = \frac{2I_D}{g_m} \leftrightarrow g_m = \frac{2I_D}{V^*}$$

For a square-law device,  $V^* = V_{ov}$ , however, for a real MOSFET they are not equal. The actual gain is now given by

$$|A_v| \approx \frac{2V_A}{V^*}$$

The lower the  $V^*$  the higher the gain, but the larger the area and the lower the speed.

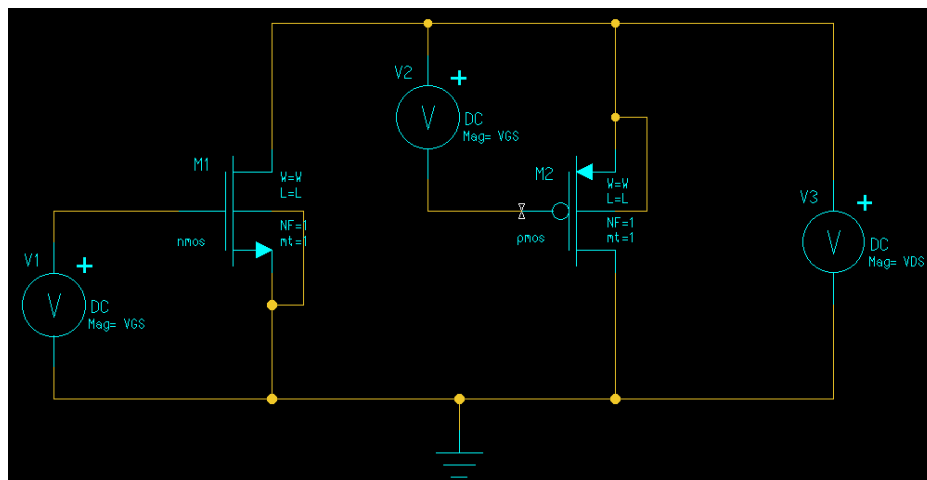
- 2) We want to design a differential amplifier with the specifications below. Note that the bias current is split between two transistors; each transistor gets  $I_D = 20\mu A$ .

Parameter	130 nm	180 nm
$L$	$1\mu m$	$1\mu m$
CM output level <sup>1</sup>	0.5	0.7
Differential gain	5	8
Supply	1.2V	1.8V
Bias current ( $I_{SS}$ )	$40\mu A$	$40\mu A$

- 3) Choose  $R_D$  to meet the CM output level spec.  
4) We can show that the differential amplifier gain is given by

$$|A_v| \approx g_m R_D = \frac{2I_D}{V^*} \times R_D = \frac{2V_{RD}}{V^*}$$

- 5) Choose  $V^*$  to meet the differential gain spec.  
6) The remaining variable in the design is to calculate  $W$ . Since the square-law is not accurate, we cannot use it to determine the sizing. Instead, we will use a sizing chart generated from simulation. Create a testbench for PMOS transistor as shown below (**we will use PMOS only in this lab**). Use  $W = 10\mu m$  (we will understand why shortly).



- 7) Sweep  $V_{GS}$  from 0 to  $\approx V_{TH} + 0.4V$  with 10mV step. Set  $V_{DS} = V_{DD}/2$ .

<sup>1</sup>  $I_{SS} \times R_D$  must be smaller than  $(V_{DD} - V_{dsat3})$  for proper large signal characteristics (why?).

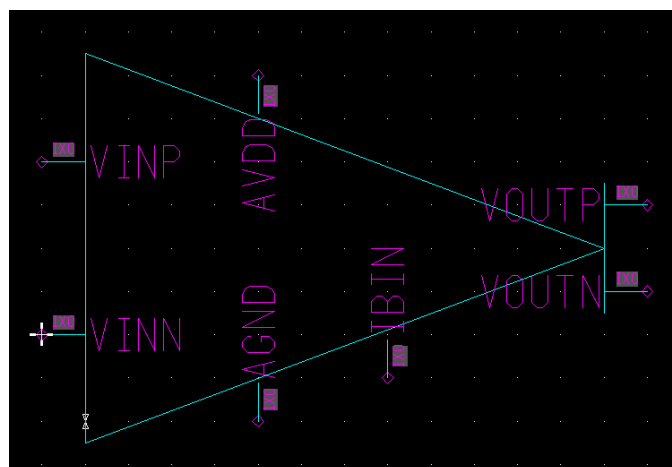
- 8) We want to compare  $V^* = 2I_D/g_m$  and  $V_{ov} = V_{GS} - V_{TH}$  by plotting them overlaid. Use the calculator to create expressions for  $V^*$  and  $V_{ov}$ . You can save the expressions to reuse them later.
- 9) Plot  $V^*$  and  $V_{ov}$  overlaid vs  $V_{GS}$ . Make sure the y-axis of both curves has the same range. You will notice that at the beginning of the strong inversion region,  $V^*$  and  $V_{ov}$  are relatively close to each other (i.e., square-law is relatively valid). For deep strong inversion (large  $V_{ov}$ : velocity saturation and mobility degradation) or weak inversion (near-threshold and subthreshold operation) the behavior is quite far from the square-law.
- 10) On the  $V^*$  and  $V_{ov}$  chart locate the point at which  $V^*$  is equal to the value your previously calculated to meet the gain spec. Find the corresponding  $V_{ovQ}$  and  $V_{GSQ}$ .
- 11) Plot  $I_D$ ,  $g_m$ , and  $g_{ds}$  vs  $V_{GS}$ . Find their values at  $V_{GSQ}$ . Let's name these values  $I_{DX}$ ,  $g_{mX}$ , and  $g_{dsX}$ .
- 12) Now back to the assumption that we made that  $W = 10\mu m$ . This is not the actual value that we will use for our design. But the good news is that  $I_D$  is always proportional to  $W$  irrespective of the operating region and the model of the MOSFET (regardless square-law is valid or no). Thus, we can use ratio and proportion (cross-multiplication) to determine the correct width at which the current will be  $I_{DQ}$  as given in the specs. Calculate  $W$  as shown below.

$W$	$I_D$
$10\mu m$	$I_{DX} @ V_Q^*$ (from the chart)
?	$I_{DQ} = 20\mu A$ (from the specs)

- 13) Now we are almost done with the design of the amplifier. Note that  $g_m$  is also proportional to  $W$  as long as  $V_{ov}$  is constant. On the other hand,  $r_o = 1/g_{ds}$  is **inversely** proportional to  $W$  ( $I_D$ ) as long as  $L$  is constant. Before leaving this part, calculate  $g_{mQ}$  and  $g_{dsQ}$  using ratio and proportion (cross-multiplication).

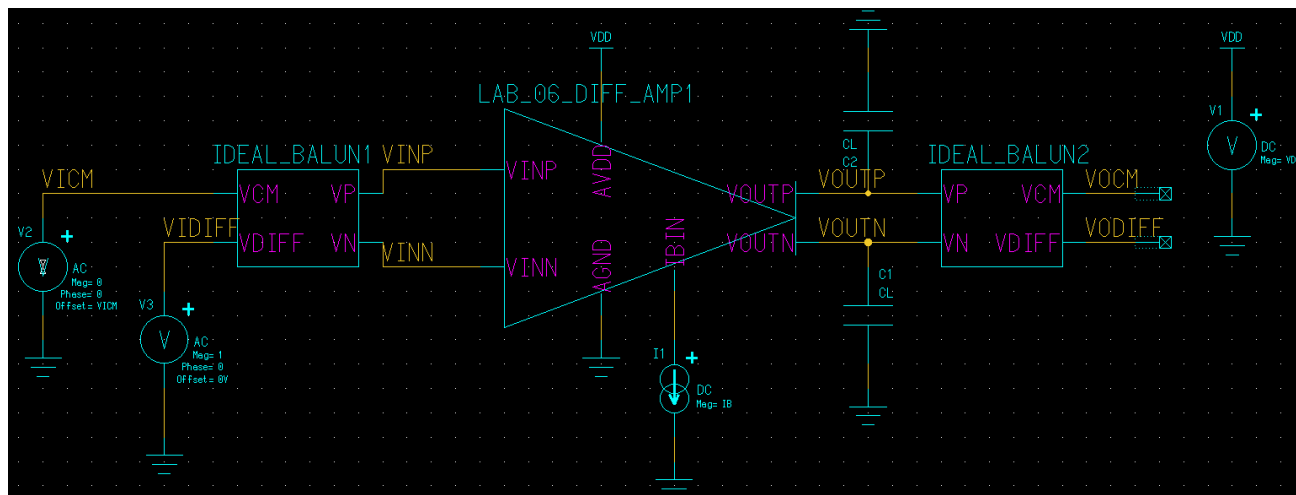
## PART 2: Differential Amplifier

- 1) Create a new cell for the diff amp "lab\_06\_diff\_amp". Create the schematic of a differential amplifier with PMOS input stage and resistive load. Use a simple current mirror for the bias current source as shown in the first figure in this document.
- 2) Create a symbol for the diff pair (use Create -> Cellview -> From Cellview).
- 3) Edit the diff amp symbol to be as shown below.



4) Create a new cell for the testbench “lab\_06\_diff\_amp\_tb”. Create testbench schematic as shown below.

→ Cadence Hint: Use ideal\_balun from analogLib to separate common-mode and differential signals. In Mentor tools you have to create the balun yourself.



5) Size the transistors as designed in Part 1.

6) Use  $I_B = 20\mu A$  (the CM multiplies this by 2, so each half in the diff pair gets  $I_B$ ).

7) Connect floating wires to noConn instance from basic library to avoid floating signal warnings.

8) Use  $C_L = 1pF$ .

9) Analytically calculate the valid range for  $V_{icm}$ : the common mode input range (CMIR). Set  $V_{icm}$  at the center of this range.

→ Cadence Hint: In adexl you can access the results of the last 10 simulation runs from the “History” tab. We want to access the last two simulation runs in order to compare  $A_{vd}$  and  $A_{vcm}$ . Open both simulations in the Results Browser.

## Report the following:

1) OP simulation.

- Report the schematic of the diff pair with DC OP point clearly annotated:  $i_d$ ,  $v_{gs}$ ,  $v_{ds}$ ,  $v_{th}$ ,  $v_{dsat}$ ,  $g_m$ ,  $g_{ds}$ ,  $g_{mb}$ , region.
- Check that all transistors operate in saturation.

2) Diff small signal ccs:

- Use AC magnitude = 1 for the diff source (and AC magnitude = 0 for the CM source).
- Set  $V_{icm}$  at the center of the CMIR.
- Run AC analysis (1Hz:10GHz, logarithmic, 10 points/decade).
- Report the Bode plot of small signal diff gain.
- Compare the DC diff gain and BW with hand analysis in a table.

3) CM small signal ccs:

- Use AC magnitude = 1 for the CM source (and AC magnitude = 0 for the diff source).
- Run AC analysis (1Hz:10GHz, logarithmic, 10 points/decade).
- Report the Bode plot of small signal CM gain.
- Compare the DC CM gain with hand analysis in a table. Is it smaller than “1”? Why?
- Justify the variation of  $A_{vcm}$  vs frequency.
- Plot  $A_{vd}/A_{vcm}$  in dB. Compare  $A_{vd}/A_{vcm}$  @ DC with hand analysis in a table.

- Justify the variation of  $A_{vd}/A_{vcm}$  with frequency.
  - Cadence Hint: Note that  $x_f$  analysis cannot be used in this case because we have two outputs (Diff and CM).  $x_f$  analysis is useful for the case of single-ended output op-amp where there is only one output terminal. It is also useful for fully diff op-amp to calculate  $CMRR(SE2diff)$ , but not  $A_{vd}/A_{vcm}$ .
- 4) Diff large signal ccs:
- Use dc sweep (not parametric sweep) for  $V_{id} = -V_{DD}:10m:V_{DD}$ . Set  $V_{icm}$  at the center of the CMIR.
  - Report diff large signal ccs ( $V_{ODIFF}$  vs  $V_{IDIFF}$ ). Compare the extreme values with hand analysis in a table.
- 5) CM large signal ccs (region vs  $V_{ICM}$ ):
- We will use the region parameter to know the operating region of each transistor vs sweep variable.
  - Cadence Hint: The “region” meaning is as follows:
    - 0: cut-off
    - 1: triode
    - 2: sat
    - 3: subth
    - 4: breakdown
  - Use DC sweep (not parametric sweep) for  $V_{icm} = 0:10m:V_{DD}$  (no need to run AC sim)
  - Cadence Hint: To save the “region” parameter, add this line to your save.scs file (in Model Libraries):
 

```
save *:region sigtype=dev.
```
  - Disable ac analysis.
  - Plot “region” OP parameter vs  $V_{ICM}$  for the input pair and the tail current source.
  - Find the CM input range (CMIR). Compare with hand analysis in a table.
  - Note that the drawback of this method is that the “region” parameter cannot be experimentally measured in the lab and is not quantitatively related to circuit specifications.
- 6) CM large signal ccs (GBW vs  $V_{icm}$ ):
- Use ac analysis (start = 1, stop = 1, pts(linear) = 1) to get  $A_{vd}$ . Use parametric sweep (not dc sweep) for  $V_{icm} = 0:20m:V_{DD}$ .
  - Cadence Hint: Instead of using parametric sweep, a better alternative in Cadence is to use AC sweep but sweep a design variable ( $V_{icm}$ ) instead of sweeping the frequency. The frequency is set at 1 Hz (or any other small value) to get the low frequency gain (DC gain).
  - Cadence Hint: Use the following expression in adexl to calculate  $A_{vd}$ :  $y_{max}(mag(VF("/V_{ODIFF}")))$
  - Note that the bandwidth is determined by  $R_D$  and  $C_L$ , thus  $A_{vd}$  variation is itself GBW variation.
  - Report CM large signal ccs ( $A_{vd}$  vs  $V_{icm}$ ). Assume the valid range for  $V_{icm}$  (CMIR) is defined by the condition that  $A_{vd}$  is within 90% of the max gain, i.e., 10% drop in gain.
  - Plot the results overlaid on the results of the previous method (region parameter). Find the CM input range. Compare with the previous method in a table.

## Lab Summary

- In Part 1 you learned:
  - How to generate and use design charts for NMOS and PMOS transistors.
  - How to design a resistive-loaded differential amplifier.

- In Part 2 you learned:
  - How to use an ideal balun.
- In Part 3 you learned:
  - How to simulate the small-signal differential gain of a differential amplifier.
  - How to simulate the small-signal common-mode gain of a differential amplifier.
  - How to simulate the large-signal differential characteristics of a differential amplifier.
  - How to simulate the large-signal common-mode characteristics of a differential amplifier.

## Acknowledgements

Thanks to all who contributed to these labs. Special thanks to Dr. Sameh A. Ibrahim for reviewing and editing the labs. If you find any errors or have suggestions concerning these labs, contact

[Hesham.omran@eng.asu.edu.eg](mailto:Hesham.omran@eng.asu.edu.eg).